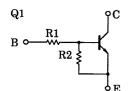
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process) Silicon PNP Epitaxial Type (PCT Process)

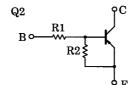
# **RN4987**

# Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Includeing two devices in US6 (Ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

#### **Equivalent Circuit and Bias Resister Values**





R1: 10kΩ R2: 47kΩ (Q1, Q2 Common)

1

#### Q1 Maximum Ratings (Ta = 25°C)

| Characteristic            | Symbol           | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage    | $V_{CBO}$        | 50     | V    |
| Collector-emitter voltage | V <sub>CEO</sub> | 50     | V    |
| Emitter-base voltage      | V <sub>EBO</sub> | 6      | V    |
| Collector current         | Ic               | 100    | mA   |

### Unit: mm 2.1 ± 0.1 1.25 ± 0.1 1. EMITTER 1 (E1) (B1) BASE 1 **COLLECTOR 2** (C2) EMITTER 2 (E2) BASE 2 (B2) US6 **COLLECTOR 1** (C1) JEDEC EIAJ TOSHIBA 2-2J1A

Weight: 6.8mg

#### Q2 Maximum Ratings (Ta = 25°C)

| Characteristic            | Symbol           | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage    | $V_{CBO}$        | -50    | V    |
| Collector-emitter voltage | V <sub>CEO</sub> | -50    | V    |
| Emitter-base voltage      | V <sub>EBO</sub> | -6     | ٧    |
| Collector current         | Ic               | -100   | mA   |

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# Q1, Q2 Common Maximum Ratings (Ta = 25°C)

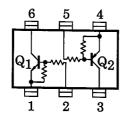
| Characteristic              | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector power dissipation | P <sub>C</sub> * | 200     | mW   |
| Junction temperature        | Tj               | 150     | °C   |
| Storage temperature range   | T <sub>stg</sub> | -55~150 | °C   |

<sup>\* :</sup> Total rating

### Marking



# **Equivalent Circuit (Top View)**



2

# Q1 Electrical Characteristics (Ta = 25°C)

| Characteristic                       | Symbol                | Test<br>Circuit | Test Condition                                       | Min   | Тур. | Max  | Unit |
|--------------------------------------|-----------------------|-----------------|--|-------|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>      | _               | V <sub>CB</sub> = 50V, I <sub>E</sub> = 0            | _     | _    | 100  | nA   |
| Concetor cut-on current              | I <sub>CEO</sub>      | _               | V <sub>CE</sub> = 50V, I <sub>B</sub> = 0            | _     | _    | 500  |      |
| Emitter cut-off current              | I <sub>EBO</sub>      | _               | V <sub>EB</sub> = 6V, I <sub>C</sub> = 0             | 0.081 | _    | 0.15 | mA   |
| DC current gain                      | h <sub>FE</sub>       | _               | V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA          | 80    | _    | _    | _    |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat) | _               | I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA        | _     | 0.1  | 0.3  | V    |
| Input voltage (ON)                   | V <sub>I (ON)</sub>   | _               | V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA         | 0.7   | _    | 1.8  | V    |
| Input voltage (OFF)                  | V <sub>I (OFF)</sub>  | _               | V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA         | 0.5   | _    | 1.0  | V    |
| Transition frequency                 | f <sub>T</sub>        | _               | V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA          | _     | 250  | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>       | _               | V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1 MHz | _     | 3    | 6    | pF   |

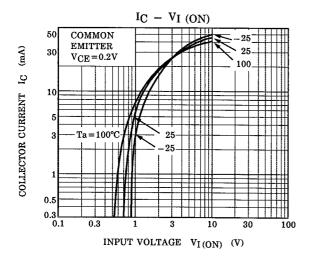
# Q2 Electrical Characteristics (Ta = 25°C)

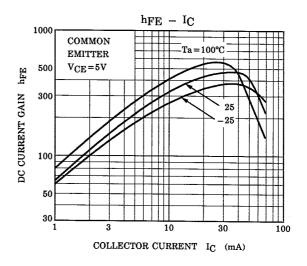
| Characteristic                       | Symbol                | Test<br>Circuit | Test Condition                                 | Min    | Тур. | Max   | Unit |
|--------------------------------------|-----------------------|-----------------|--|--------|------|-------|------|
| Collector cut-off current            | I <sub>CBO</sub>      | _               | $V_{CB} = -50V, I_E = 0$                       | _      | _    | -100  | nA   |
| Collector cut-on current             | I <sub>CEO</sub>      | _               | $V_{CE} = -50V, I_B = 0$                       | _      | _    | -500  | ш    |
| Emitter cut-off current              | I <sub>EBO</sub>      | _               | $V_{EB} = -6V, I_C = 0$                        | -0.081 | _    | -0.15 | mA   |
| DC current gain                      | h <sub>FE</sub>       | _               | $V_{CE} = -5V, I_{C} = -10mA$                  | 80     | _    | _     | _    |
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | _               | $I_C = -5mA$ , $I_B = -0.25mA$                 | _      | -0.1 | -0.3  | V    |
| Input voltage (ON)                   | V <sub>I (ON)</sub>   | _               | V <sub>CE</sub> = -0.2V, I <sub>C</sub> = -5mA | -0.7   | _    | -1.8  | V    |
| Input voltage (OFF)                  | V <sub>I (OFF)</sub>  | _               | $V_{CE} = -5V, I_{C} = -0.1 \text{mA}$         | -0.5   | _    | -1.0  | V    |
| Transition frequency                 | f <sub>T</sub>        | _               | $V_{CE} = -10V, I_{C} = -5mA$                  | _      | 200  | _     | MHz  |
| Collector output capacitance         | C <sub>ob</sub>       | _               | V <sub>CB</sub> = −10V, I <sub>E</sub> = 0     | _      | 3    | 6     | pF   |

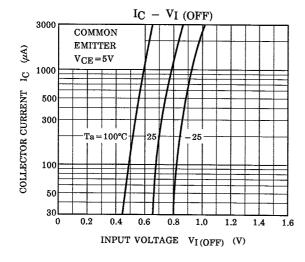
### Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test<br>Circui<br>t | Test Condition | Min   | Тур.  | Max   | Unit |
|----------------|--------|---------------------|----------------|-------|-------|-------|------|
| Input resistor | R1     | _                   | _              | 7     | 10    | 13    | kΩ   |
| Resistor ratio | R1/R2  | _                   | 1              | 0.191 | 0.213 | 0.232 | _    |

Q1

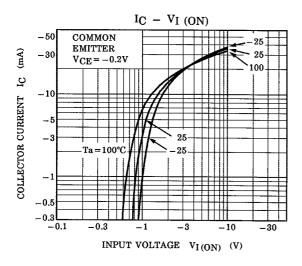


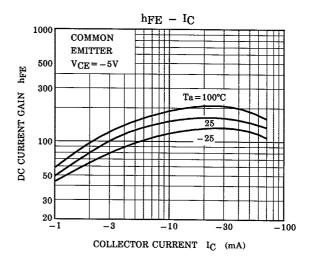


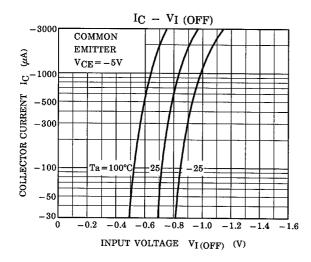


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Q2







5

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